

TGL2206–SM 2.0–5.5 GHz 100 Watt VPIN Limiter

Product Overview

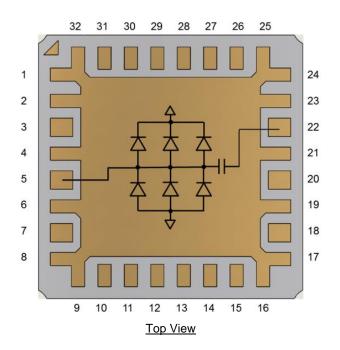
The Qorvo TGL2206-SM is a high power, wideband GaAs VPIN limiter capable of protecting sensitive receive channel components against high power incident signals. The TGL2206-SM does not require DC bias and achieves a low insertion loss all in a small form factor. These features allow for simple integration with minimal impact to system performance.

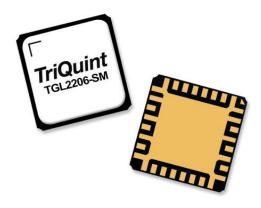
The TGL2206-SM operates from 2.0 to 5.5 GHz with low insertion loss of less than 1.0 dB. It can limit up to 100 W incident pulsed power with a low flat leakage of less than 15.5 dBm.

The TGL2206-SM is offered in a 5x5 mm air-cavity QFN packaged limiter comprised of an aluminum-nitride base with a plastic epoxy-sealed lid. It is well suited for both commercial and defense related applications.

Lead-free and RoHS compliant.

Functional Block Diagram





5 mm x 5 mm Air Cavity QFN Package

Key Features

• Frequency Range: 2.0 to 5.5 GHz

• Insertion Loss: < 1.0 dB

• Peak Power Handling: 100 W (pulsed)

• Flat Leakage: < 15.5 dBm

• Passive (no DC bias required)

· Integrated DC Block on Output

Spike Leakage < 16 dBm

• Recovery Time < 115 ns

• Package Dimensions: 5.0 x 5.0 x 1.45 mm

Performance is typical across frequency. Please reference electrical specification table and data plots for more details.

Applications

- Receive Chain Protection
- · Commercial and Military Radar

Ordering Information

Part	Description
TGL2206-SM	2.0 to 5.5 GHz 100W
	VPIN Limiter
TGL2206-SMEVB-01	2.0 to 5.5 GHz 100W VPIN Limiter EVB



Absolute Maximum Ratings

Parameter	Rating
Incident Power, CW or Pulsed, 50 $\Omega,$ 25 $^{\circ}\text{C}$	100 W
Incident Power, CW or Pulsed, 50 Ω , 85 °C	70 W
Mounting Temperature (30 seconds max)	260 °C
Storage Temperature	-40 to 150 °C

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability.

Recommended Operating Conditions

Parameter	Min	Тур.	Max	Units
Passive – No Bias				
Operating Temperature Range	-40	+25	+85	°C

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications

Parameter	Min	Typical	Max	Units
Operational Frequency Range	2		5.5	GHz
Insertion Loss		< 1.0		dB
Input Return Loss		15		dB
Output Return Loss		15		dB
Flat Leakage Power at P _{IN} > 30 dBm		< 15		dBm
Pulse Recovery Time		< 115		ns
Spike Leakage		< 16		dBm
Insertion Loss Temperature Coefficient		0.003		dB / °C

Notes: Test conditions unless otherwise noted: Temp = +25 °C, Tuned EVB Results.

Thermal and Reliability Information

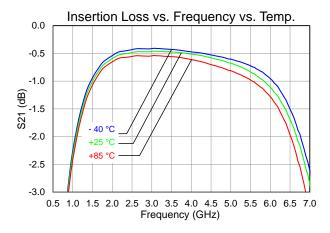
Parameter	Test Conditions	Value	Units
Incident Power (168 Hours RF Operational Life Test ⁽¹⁾)	Frequency = 4.5 GHz RF CW, 50 Ω , 25 °C	50	W
	Frequency = 4.5 GHz RF Pulsed, PW=10 μ s, DC=10%, 50 Ω , 25 °C	100	W

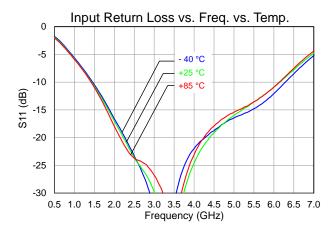
Notes: (1) Test terminated after 168 hours. Insertion Loss remained ≤ 1 dB for device under test.

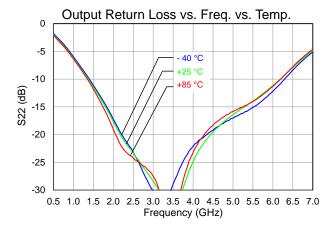


Performance Plots – Small Signal

Test conditions unless otherwise noted: Temp.=+25 °C, Tuned EVB Performance



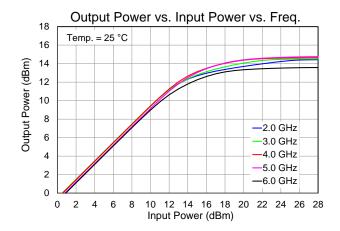


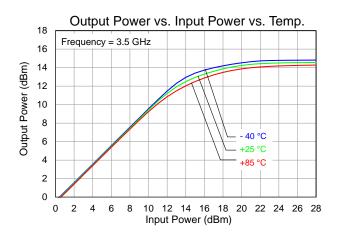


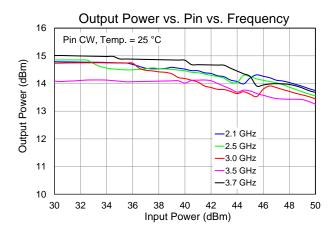


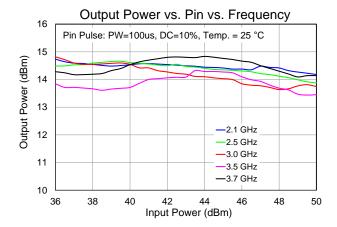
Performance Plots –Large Signal

Test conditions unless otherwise noted: CW input power, Temp.=+25 °C, Tuned EVB Performance



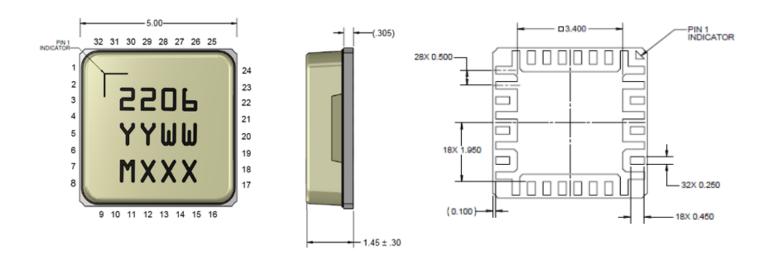








Mechanical Drawing and Pad Configuration



The TGL2206-SM will be marked with the "YYMM" designator and a lot code marked below the part designator. The "YY" represents the last two digits of the year the part was manufactured, the "WW" is the work week, and the "MXXX" is the batch ID.

The package base is ceramic and the plating material on the leads is gold over nickel (Au-Ni), the lid is plastic, the part is epoxy sealed.

Dimensions Units: mm. Tolerance unless specified: .xx = +/-0.25, .xxx = +/-0.127

Pad No.	Label	Description
1,2,4,6,8,9,16,17,19,21,23, 24, 25, 32	GND	On PCB, multiple copper-filled vias should be employed under the center pad to minimize inductance and thermal resistance. See page 6 for suggested mounting configuration
5	RF Input	RF Input, matched to 50 Ohms, not DC blocked
22	RF Output	RF Output, matched to 50 Ohms, DC blocked
3,7,10-15,18,20, 26-31	NC	No connection, may be grounded if desired

NOTE: The RF Input and RF Output ports are not interchangeable.

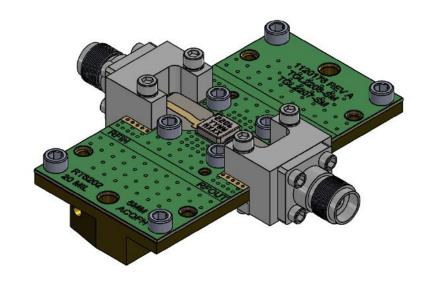


EVB and Device Mounting Details

EVB Descriptions

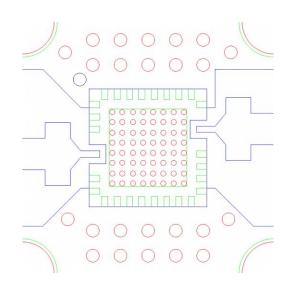
EVB PCB is 0.020" thick Rogers RO6202, ε_{Γ} = 2.94. Metal layers are 1-oz copper. Microstrip 50 Ω line width is 0.050". The microstrip line taper at the connector interface is optimized for the Southwest Microwave end-launch connector 1092-02A-5.

The pad pattern shown has been developed and tested for optimized assembly at Qorvo Inc. The PCB land pattern has been developed to accommodate lead and package tolerances. Since surface mount processes vary from company to company, careful process development is recommended.



Device Mounting Details

- Ground / thermal vias under the device are critical for the proper performance of this device.
- The EVB shown herein utilizes copper filled vias (8 mil diameter) under the device to maximize heat transfer away from the device under large signal conditions.
- 3. Thermal dissipation is low for normal non-limiting operation.





Assembly Notes

- Compatible with lead-free soldering process with 260°C peak reflow temperature.
- This package is non-hermetic, and therefore cannot be subjected to aqueous washing. The use of no-clean solder to avoid washing after soldering is recommended
- Solder rework not recommended.
- Contact plating: Ni-Au

Recommended Soldering Profile

